

Series PVX6012

Microelectronic Power IC Relay

IGBT Photovoltaic Relay

Single Pole, Normally Open,

0-280VAC (RMS) or 0-400VDC, 1.0A AC/DC

General Description

The PVX6012 Photovoltaic Relay is a single-pole, normally open solid-state relay that can replace electromechanical relays in many applications. It utilizes an IGBT output switch, driven by an integrated circuit photovoltaic generator of novel construction. The output switch is controlled by radiation from a GaAlAs light emitting diode (LED) which is optically isolated from the photovoltaic generator.

The PVX6012 is ideally suited for switching medium power loads. It offers high operating speed, low and stable on-state voltage drop as well as low off-state leakage current.

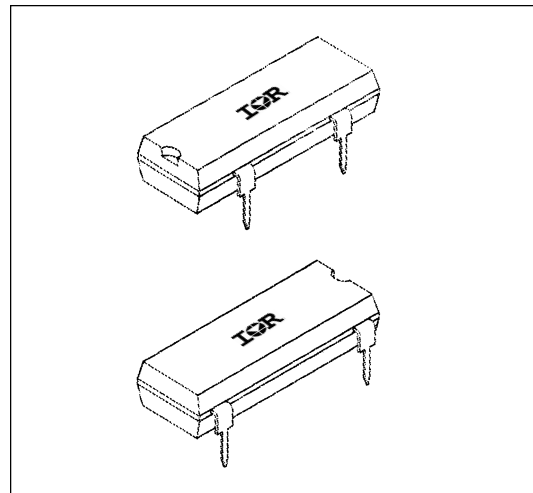
PVX6012 relays are packaged in a 14-pin, molded DIP package in thru-hole. It is available in standard plastic shipping tubes.

Applications

- Test Equipment
- Industrial Controls and Automation
- Electromechanical Relay Replacement
- Mercury-wetted Relay Replacement

Features

- IGBT and HEXFRED™ output
- Bounce-free operation
- 3,750 V_{RMS} I/O isolation
- High load current capacity
- Low off-state leakage current
- Solid-State reliability
- UL recognized and CSA certified



Part Identification

PVX6012 through-hole

PVX6012

Electrical Specifications (-40°C ≤ T_A ≤ +85°C unless otherwise specified)

INPUT CHARACTERISTICS	Limits	Units
Minimum Control Current (see figure 1)	5.0	mA
Maximum Control Current for Off-State Leakage @T _A =+25°C	0.4	mA
Control Current Range (Caution: current limit input LED, see figure 6)	5.0 to 25	mA
Maximum Reverse Voltage	7.0	V

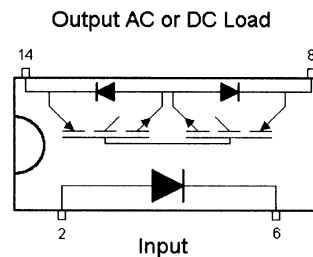
OUTPUT CHARACTERISTICS	Limits	Units
Transient Overvoltage Protection	600	V(DC or AC peak)
Operating Voltage	0-280 0-400	V(AC) RMS V(DC)
Maximum Load Current @ T _A = +40°C	1.0	A(DC)
5mA Control (see figure 1 and Note 1)	1.0	A (AC) RMS
Maximum Surge Current		
non-repetitive, 1 sec.	5	A(DC)
non-repetitive 20 msec. (see figure 2)	20	A(DC)
Maximum On-State Voltage Drop @T _A =+25°C	2.5	V
For 1A pulsed load, 5mA Control (see figures 3 and 4)		
Maximum Off-State Leakage @T _A =+25°C, ± 400V (see figure 5)	10	μA
Maximum Turn-On Time @T _A =+25°C (see figure 8)	7	ms
For 1A, 400 V _{DC} load, 5mA Control		
Maximum Turn-Off Time @T _A =+25°C (see figure 8)	1	ms
For 1A, 400 V _{DC} load, 5mA Control		
Maximum Output Capacitance @ 100V _{DC} (see figure 7)	50	pF

GENERAL CHARACTERISTICS	Limits	Units
Minimum Dielectric Strength, Input-Output	3750	V _{RMS}
Minimum Insulation Resistance, Input-Output	10 ¹²	Ω
@T _A =+25°C, 50%RH, 100V _{DC}		
Maximum Capacitance, Input-Output	1.0	pF
Maximum Pin Soldering Temperature (10 seconds maximum)	+260	
Ambient Temperature Range:		°C
Operating	-40 to +85	
Storage	-40 to +100	

Connection Diagram

Notes:

- ① Load handling capability to 0.2 power factor requires overvoltage protection.



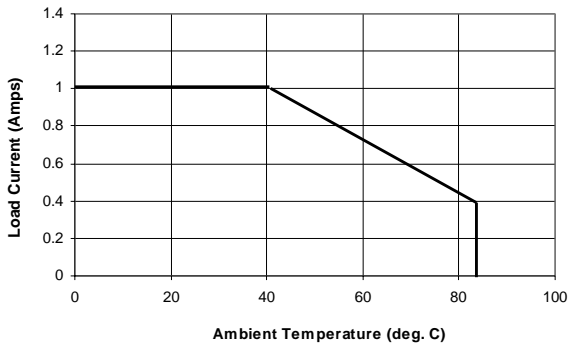


Figure 1. Current Derating Curve

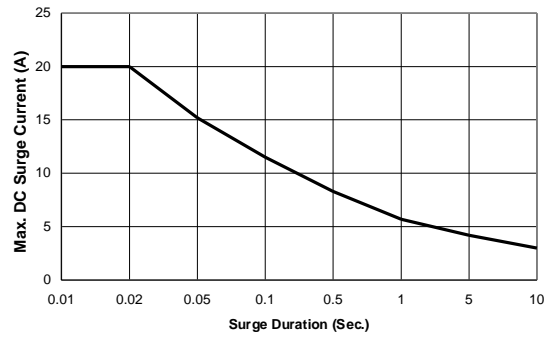


Figure 2. Surge Current Capability

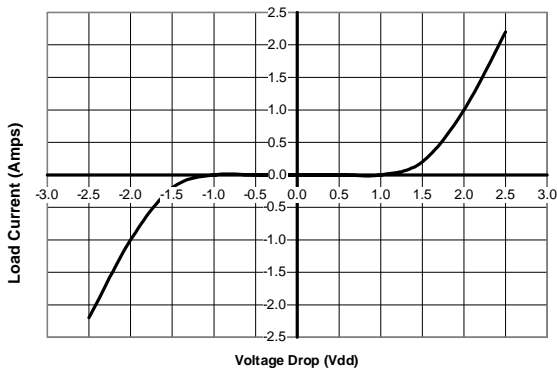


Figure 3. Output Characteristics

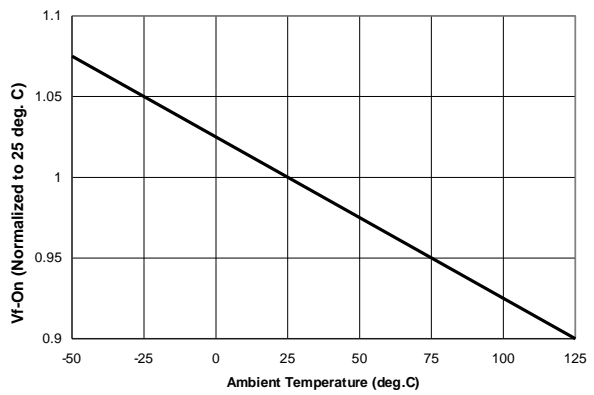


Figure 4. Typical Normalized VCEON

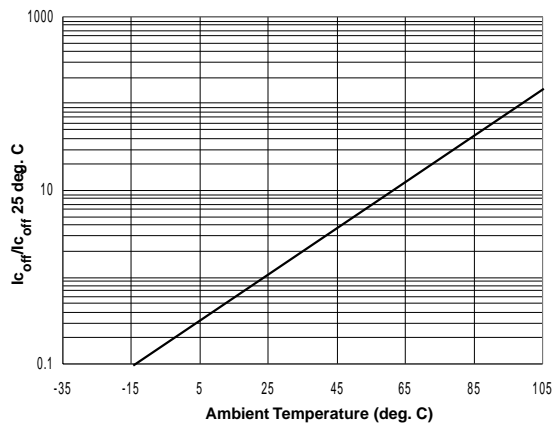


Figure 5. Typical Normalized Off-State Leakage

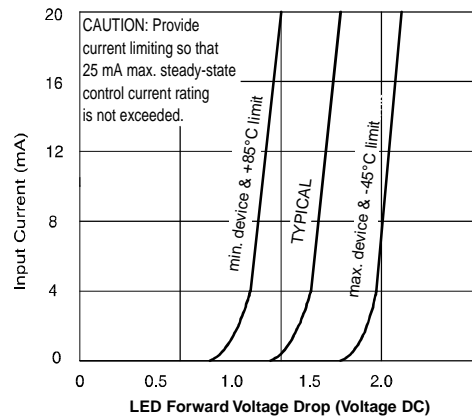


Figure 6. Input Characteristics (Current Controlled)

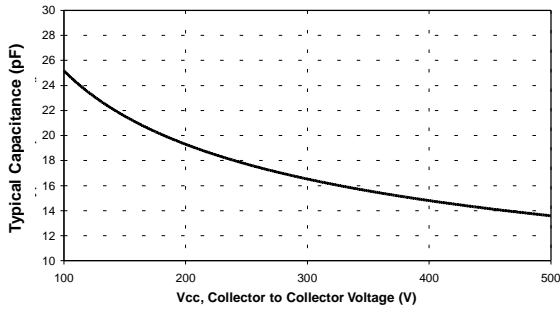


Figure 7. Typical Output Capacitance

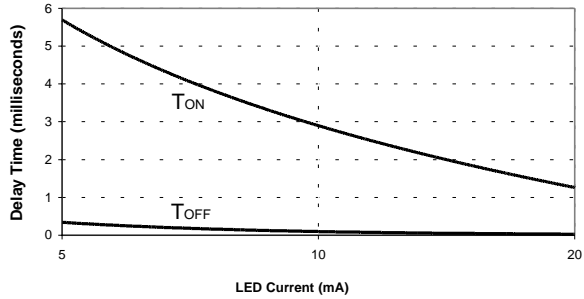


Figure 8. Typical Delay Times

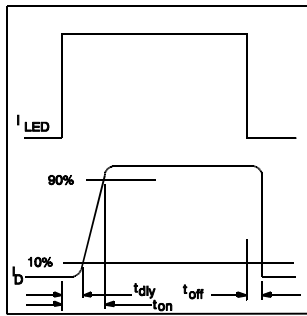
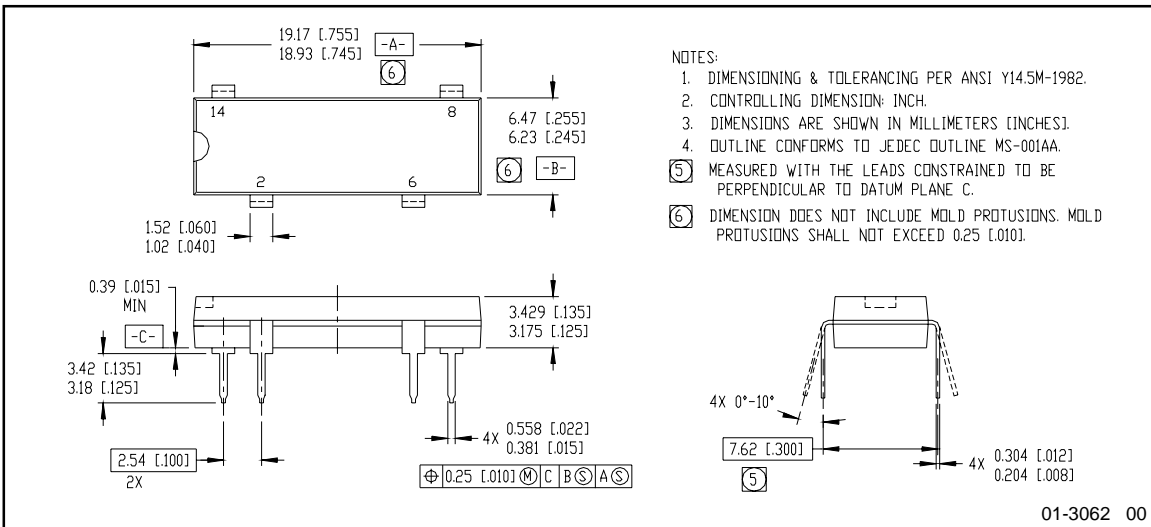


Figure 9. Delay Time Definitions

Case Outline



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